Nonequilibrium dynamical ferromagnetism of interacting Single-Molecule Magnets

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We propose a nonequilibrium Monte Carlo (MC) approach to explore nonequilibrium dynamical ferromagnetism of interacting single molecule magnets (SMMs). Both quantum spin tunneling and thermally activated spin reversal are successfully implemented in the same MC simulation framework. Applied to a typical example, this simulation method satisfactorily reproduces experimental magnetization curves with experimental parameters. Our results show that both quantum and classical effects are essential to determine the hysteresis behaviors. This method is effective and reliable to gain deep insights into SMMs.

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Introduction. The single-molecule magnet (SMM) is very interesting because of its potential applications in spintronic devices[\[1](#page-2-1), [2\]](#page-2-2), quantum computing[\[3](#page-2-3)], information storage[\[4\]](#page-2-4), optical transistors[\[5\]](#page-2-5), and so on. The most famous examples are $Mn_{12}[6, 7]$ $Mn_{12}[6, 7]$ $Mn_{12}[6, 7]$ $Mn_{12}[6, 7]$, Fe₈[\[8](#page-2-8)], and $Mn_4[9]$ $Mn_4[9]$. A SMM usually has well-defined spin ground state and large magnetic anisotropy, and can exhibit hysteresis loops at low enough temperatures[\[10\]](#page-2-10). Landau-Zener[\[11](#page-2-11), [12](#page-2-12)] (LZ) model has been used to explain the steps of the hysteresis loops[\[10,](#page-2-10) [13](#page-2-13), [14](#page-2-14)]. On theoretical side, numerically exact method has been used to the phenomenological spin model for the $Fe₈$ and $Mn₁₂$ systems, and calculated results show that LZ model is reliable for usual experimental field sweeping rates in describing the two-level problems at the level crossing fields[\[15,](#page-2-15) [16](#page-2-16)], but experimental hysteresis loops cannot be explained because thermally activated processes are not considered[\[10](#page-2-10)]. Thermally activated processes, however, play important roles in determining the nonequilibrium magnetization dynamics and even level populations. A quantitative method which is able to reproduce the full hysteretic magnetization dynamics of SMMs is in need.

Here, we propose a nonequilibrium Monte Carlo (NQMC) approach taking both the LZ quantum tunneling effect and the thermally activated processes into account, and hereby satisfactorily reproduce and explain experimental magnetization behaviors of SMMs.

Spin model. For simplicity without losing physics, we arrange SMMs on a finite two-dimensional (2D) rectangular lattice of $L_1 \times L_2$, and consider inter-SMM magnetic dipolar and exchange interactions. Actually, some single layers of patterned SMMs has already been grown on specific solid surfaces[\[17,](#page-2-17) [18,](#page-2-18) [19\]](#page-2-19), and it has been proved that a SMM, when put on a Au surface, can still keep its essential properties[\[4\]](#page-2-4). We use giant spin approximation. Every SMM has a spin of S . We use a typical lattice constant $a = 1.5$ nm, which is an intermediate value of well-known SMMs. The model Hamiltonian reads

$$
H = \sum_{i} H_i^0 + \frac{1}{2} \sum_{i \neq j} (J_{ij}^{di} - J_{ij}) \mathbf{S}_i \cdot \mathbf{S}_j , \qquad (1)
$$

where J_{ij}^{di} and J_{ij} describe the magnetic dipolar and exchange interactions between spins at i and j . The factor 1/2 is due to the double counting in the summation. The first term describes the part for all the single SMMs, and H_i^0 is given by

$$
H_i^0 = -D_2(\hat{S}_i^z)^2 - D_4(\hat{S}_i^z)^4 + H_i^{\text{tr}} + g\mu_B B_z \hat{S}_i^z , \quad (2)
$$

where D_2 and D_4 are positive anisotropic parameters, g the Landé g-factor (here $q=2$ is used), μ_B the Bohr magneton, $B_z(t)$ the external magnetic field in the z direction. $\hat{S}_i = (\hat{S}_i^x, \hat{S}_i^y, \hat{S}_i^z)$ is the quantum spin operator for the *i*th SMM. As for the transverse term H_i^{tr} , it is usually defined as $H_i^{\text{tr}} = E[(\hat{S}_i^x)^2 - (\hat{S}_i^y)^2] + g\mu_B B_x \hat{S}_i^x$, where E is the second-order transverse anisotropic constant and B_x is the transverse external field in the x direction. As usual, B_x is a constant and $B_z(t)$ is a linear function of the time t with the sweeping rate ν .

LZ tunneling probability. The easy axis determines two equilibrium spin directions in the $\pm z$ direction. When calculating the LZ tunneling probability, we treat the SMM spins coupled with the ith spin by using the mean field approximation. As a result, for the ith SMM, we have the effective one-SMM Hamiltonian

$$
H_i = H_i^0 + g\mu_B B_i^{\text{eff}} \hat{S}_i^z \tag{3}
$$

where the effective mean field B_i^{eff} is given by

$$
B_i^{\text{eff}} = \sum_{j(\neq i)} (J_{ij}^{\text{di}} - J_{ij}) S_j^{\text{eq}} / (g\mu_B) , \qquad (4)
$$

where S_j^{eq} is the equilibrium value (S or $-S$) for the *i*th spin along the easy axis. This approximation is natural in the NQMC simulation, as will be clarified in the following. Then the standard diagonalization technique can be used to solve Eq. [\(3\)](#page-0-0). Hamiltonian Eq. [\(3\)](#page-0-0) has $2S+1$ energy levels, which can be labeled by the quantum numbers $m = S, S-1, \dots, -(S-1), -S$ to a first-order approximation. If without the transverse part H_i^{tr} , Eq. [\(3\)](#page-0-0) is diagonal, and there are level crossings at some special field values. When the transverse term H_i^{tr} is taken into account, the level crossings become avoided[\[10,](#page-2-10) [13,](#page-2-13) [14\]](#page-2-14). When B_z is swept close to $B_{m,m'}$ at which the avoided level crossing happens between states m and m' , quantum tunneling occurs between the two states. Strictly speaking, this tunneling is beyond LZ model which is a two-states theory[\[11](#page-2-11), [12\]](#page-2-12), but LZ tunneling can be used as a good approximation for each of the tunneling processes because LZ transition time is usually very short compared to time increments between the two successive avoided level crossings [\[15](#page-2-15), [16](#page-2-16), [20\]](#page-2-20). The nonadiabatic LZ tunneling probability $P_{m,m'}$ is given by [\[11,](#page-2-11) [12\]](#page-2-12)

$$
P_{m,m'} = 1 - \exp\left[-\frac{\pi \Delta_{m,m'}^2}{2\hbar g \mu_B |m - m'| \nu}\right],
$$
 (5)

where the tunnel splitting $\Delta_{m,m'}$ describes the energy gap at the avoided crossing of states m and m'. $B_{m,m'}$ and $\Delta_{m,m'}$ can be calculated by diagonalizing Eq. [\(3\)](#page-0-0).

Thermally activated reversal rate. In order to calculate thermal spin reversal rate, we use classical spin approximation which is reasonable and reliable because the spin usually is very large for SMMs. As a result, the energy of the ith SMM is given by

$$
E_i = -D_2(S_i^z)^2 - D_4(S_i^z)^4 + h_i S_i^z \tag{6}
$$

where $h_i = g\mu_B (B_z + B_i^{\text{eff}})$. Each of the spins has two equilibrium orientations $(\pm S)$ along the easy axis. We use the angle θ_i to describe the *i*th spin's deviation from its original equilibrium orientation. All the other angle values $(0 < \theta_i < \pi)$ are the transition states for the spin to reverse its orientation. We express S_i^z as $S_i^{\text{eq}} \cos \theta_i$. Usually, there exists a maximum in the curve of $E_i(\cos \theta_i)$, and the maximum determines the energy barrier for the spin reversal [\[21,](#page-2-21) [22](#page-2-22)]. Defining $x_i = \cos \theta_i$, we have $-1 \leq x_i \leq 1$. Then the barrier is given by

$$
\Delta E_i = \begin{cases} E_i(x_i = x_i^m) & \text{if } |x_i^m| \le 1\\ E_i(x_i = -1) = 2|h_i S_i^{\text{eq}}| & \text{if } x_i^m < -1\\ E_i(x_i = 1) = 0 & \text{if } x_i^m > 1 \end{cases} \tag{7}
$$

where x_i^m (according to the maximum) is defined as

$$
x_i^m = \sqrt[3]{-\frac{q}{2} + \sqrt{\Delta_d}} + \sqrt[3]{-\frac{q}{2} - \sqrt{\Delta_d}} , \qquad (8)
$$

where $\Delta_d = (q/2)^2 + (p/3)^3$, $p = D_2/(2D_4S^2)$, and $q = -h_i S_i^{\text{eq}}/(4D_4S^4)$. Then the reversal rate of the ith spin is determined by the Arrhenius law[\[23\]](#page-2-23), $R_i =$ $R_0 \exp(-\Delta E_i/(k_B T))$, where k_B is the Boltzmann constant and R_0 the characteristic attempt frequency.

Simulation method and parameters. To set up our NQMC simulation, we define MC steps by the time points, $t_n = \Delta t \cdot n$, where n nonnegative integers. Every spin takes either S or $-S$ at each of the times t_n . A spin can be reversed by overcoming the thermal barrier and tunneling through LZ mechanism. The probability P_i for

FIG. 1: (color online). Simulated magnetization curves $(M/M_s \text{ vs. } B_z \text{ in T})$ with three sweeping rates: $\nu = 0.002$ (a), 0.02 (b), and 0.14 (c) T/s . For all the three panels, the temperatures are $T = 0.10$ (\bullet), 0.20 (\bullet), 0.30 (\bullet), 0.40 (\blacktriangledown), 0.50 (\blacklozenge), 0.60 (\times), 0.70 (\heartsuit), and 1.00 (\Box) K.

a thermally activated spin reversal within a MC step is defined by $P_i = \Delta t \cdot R_i[21, 22]$ $P_i = \Delta t \cdot R_i[21, 22]$ $P_i = \Delta t \cdot R_i[21, 22]$ $P_i = \Delta t \cdot R_i[21, 22]$, and the LZ tunneling probability is given by Eq. [\(5\)](#page-1-0). Actually, we have the magnetization $m = S$ at the beginning of field sweeping, and then need to consider only the avoided crossings at (S, m') , where $m' = -S, -S + 1, \cdots$. When the field is swept to $B_{S,m'}$, we consider the LZ tunneling by adding the LZ probability $P_{S,m'}$ to the thermally activated reversal probability. Because our Monte Carlo time step is much larger than the LZ transition and spin relaxation times, a spin will have long enough time to transit to the possible lowest level at current field after a LZ tunneling is finished[\[24](#page-2-24)]. Therefore, our NQMC simulation is self-consistent.

For convenience in comparing with experiment, we choose the Mn_4 system to demonstrate the NQMC method and its power. Hence we have $S = 9/2$, $D_2/k_B =$ 0.608K, $D_4/k_B = 3.8 \text{mK}$, and $E/k_B = 32 \text{mK}$ from Ref. [14](#page-2-14). We assume that our 2D lattice is put on a metal surface and hence use a carrier-mediated 2D interaction for J_{ij} ($J/k_B = 5.8 \text{mK}$ for the nearest spins)[\[25\]](#page-2-25). This inter-SMM interaction, weak enough, does not destroy the essential SMM properties. In addition, we already

show that simulated results are not sensitive to specific choices of the interaction, and other interactions yield similar results. We take $B_x = 0.02$ T, $\Delta t = 1$ ms, and $R_0 = 10^9$ /s. Such parameter choices guarantee the good balance between computational demand and precision. In our simulations, field B_z is swept from -2.5T to 2.5T in the forward process, and the full hysteresis loop is obtained simply by using the loop symmetry. Every hysteresis loop is calculated by averaging over 100 runs to reduce statistical errors.

Simulated results and discussions. We have done our NQMC simulations with various (L_1, L_2) values and experimentally accessible sweeping rates ν (0.002∼0.14 T/s) and temperatures T $(0.10~1.00~\text{K})$ [\[14](#page-2-14)]. Presented in Fig. 1 are our simulated magnetization M (normalized to the saturated value M_s) curves against the applied sweeping field B_z with $L_1 = L_2 = 10$ for three sweeping rates, namely 0.002, 0.02, and 0.14 T/s . For each of the three cases, we present the results for eight temperatures: 0.10, 0.20, 0.30, 0.40, 0.50, 0.60, 0.70, and 1.00 K. It is clear that there exist hysteresis loops for low enough temperatures and complete paramagnetic magnetizations are obtained for high enough temperatures. We can clearly see four steps between 0 and 2T for low enough temperatures. In addition, we have done NQMC simulations for various values of L_1 and L_2 . For square lattices $(L = L_1 = L_2)$, the step heights decrease a little with increasing L from 8 to 50. For rectangular lattices with $L_1 \times L_2 = 24^2$, the step heights change a little for different L_1 and L_2 . It is clear that the step structures are far from those predicted by LZ tunneling alone.

In fact, thermally activated reversals play important roles in determining the magnetization curves. Our simulations show that the number of the steps decreases with increasing the temperature for given value of the sweeping rate ν . It can be seen that the area enclosed by a hysteresis loop increases monotonically with increasing the sweeping rate and decreasing the temperature, and the smallest visible loop is at 0.70 K for $\nu = 0.14 \text{ T/s}$, 0.60 K for 0.02 T/s, and 0.50 K for 0.002 T/s, respectively. The thermal effect increases substantially when we increase the temperature from 0.3K on. There will be no step structures for usual sweeping rates when the temperature is higher than 0.5K. The hysteresis loop will disappear when the temperature is too high.

Conclusion. We have proposed a NQMC approach to explore the nonequilibrium dynamical ferromagnetism of interacting SMMs. Both quantum spin tunneling and thermally activated spin reversal are successfully implemented in the same Monte Carlo simulation framework. Applied to the Mn_4 system, this simulation method satisfactorily reproduces experimental magnetization curves with experimental parameters. Our results show that both quantum and classical effects are essential to determine the hysteresis loops in the magnetization curves. This method is effective and reliable, and can be used to gain deep insights into SMMs and other quantum nanomagnets with strong anisotropy.

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- [1] A. R. Rocha, V. M. García-suárez, S. W. Bailey, C. J. Lambert, J. Ferrer, and S. Sanvito, Nature Mater. 4, 335 (2005).
- [2] L. Bogani and W. Wernsdorfer, Nature Mater. 7, 179 (2008).
- [3] M. N. Leuenberger and D. Loss, Nature 410, 789 (2001).
- [4] M. Mannini, F. Pineider, P. Sainctavit, C. Danieli, E. Otero, C. Sciancalepore, A. M. Talarico, M.-A. Arrio, A. Cornia, D. Gatteschi, and R. Sessoli, Nature Mater. 8, 194 (2009).
- [5] J. Hwang, M. Pototschnig, R. Lettow1, G. Zumofen, A. Renn, S. Götzinger1, and V. Sandoghdar, Nature 460, 76 (2009).
- [6] T. Lis, Acta Crystallogr., Sect. B 36, 2042 (1980).
- [7] R. Sessoli, D. Gatteschi, A. Caneschi, and M. A. Novak, Nature 365, 141 (1993).
- [8] K. Weighardt, K. Pohl, I. Jibril, and G. Huttner, Angew. Chem. Int. Ed. 23, 77 (1984).
- [9] J. S. Bashkin, H. R. Chang, W. E. Streib, J. C. Huffman, D. N. Hendrickson, and G. Christou, J. Am. Chem. Soc. 109, 6502 (1987).
- [10] D. Gatteschi, R. Sessoli, and J. Villain, Molecular nanomagnets, Oxford University Press, New York, 2006.
- [11] L. Landau, Phys. Z. Sowjetunion 2, 46 (1932).
- [12] C. Zener, Proc. R. Soc. London, Ser. A 137, 696 (1932).
- [13] W. Wernsdorfer, R. Sessoli, A. Caneschi, D. Gatteschi, A. Cornia, and D. Mailly, J. Appl. Phys. 87, 5481 (2000).
- [14] W. Wernsdorfer, S. Bhaduri, A. Vinslava, and G. Christou, Phys. Rev. B 72, 214429 (2005).
- [15] E. Rastelli and A. Tassi, Phys. Rev. B 64, 064410 (2001).
- [16] P. Földi, M. G. Benedict, J. M. Pereira, Jr., and F. M. Peeters, Phys. Rev. B 75, 104430 (2007).
- [17] G. G. Condorelli, A. Motta, I. L. Fragal, F. Giannazzo, V. Raineri, A. Caneschi, and D. Gatteschi, Angew. Chem. Int. Ed. 43, 4081 (2004).
- [18] A. Naitabdi, J.-P. Bucher, P. Gerbier, P. Rabu, and M. Drillon, Adv. Mater. 17, 1612 (2005).
- [19] J. Gómez-Segura, J. Veciana, and D. Ruiz-Molina, Chem. Commun. 2007, 3699 (2007).
- [20] N. V. Vitanov, Phys. Rev. A **59**, 988 (1999).
- [21] Y. Li and B.-G. Liu, Phys. Rev. Lett. **96**, 217201 (2006); Phys. Rev. B 73, 174418 (2006).
- [22] B.-G. Liu, K.-C. Zhang, and Y. Li, Front. Phys. China 2, 424 (2007).
- [23] S. Arrhenius, Z. Phys. Chem. 4, 226 (1889).
- [24] K. Saito, S. Miyashita, and H. De Raedt, Phys. Rev. B 60, 14553 (1999).
- [25] M. T. Béal-Monod, Phys. Rev. B 36, 8835 (1987); D. N. Aristov, Phys. Rev. B 55, 8064 (1997).